Ultra-Sharp and Highly Tolerant Waveguide Bends for InP Photonic Membrane Circuits

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Abstract—In this letter, we present a sharp bend design for the InP-based photonic membrane, which shows low loss and high tolerance. The traditional arc bends on InP membranes face high loss when the bending radii reduce below 2 μm. In addition, their performance deteriorates even more dramatically at the presence of waveguide footings. The proposed design has the advantages of low loss, high compactness, wide spectral response, and ease of fabrication. It is also verified to be much more resilient to design and fabrication variations, such as waveguide footings. The sharp bend is fabricated together with traditional arc bends. Experimental results confirm its potential as a basic building block for InP photonic membrane platforms.

Index Terms—Waveguides, bends, photonic integrated circuit.

I. INTRODUCTION

PHOTONIC membrane technologies [1]–[3] are intensively studied over the past decade as promising candidates for the next-generation photonic integrated circuits (PICs). One of the most important advantages of membrane technology is the compact device size. The optical confinement in membrane waveguides can be greatly enhanced by using an optical buffer layer between the membrane and the substrate. The optical buffer layer can be SiO₂ for silicon-based membrane platforms [3] or polymer/SiO₂ for indium phosphide (InP) based membrane platforms [1], [2]. As a result, the waveguide dimensions are reduced down to the sub-micron range.

Waveguide bends are critical components in realizing complex photonic circuits [4]. The bends have to be both compact and low-loss for maximized circuit integration density and performance. This is especially important in applications such as on-chip optical interconnects [5], with very strict space and power consumption limits. On silicon membranes, waveguide bending radius as small as 1 μm has been demonstrated [6] with 90° bending loss of 0.09 dB. The loss can be further reduced with special spline designs [7].

The situation on InP membranes is quite different. The refractive index of InP (n = 3.16) is lower than that of silicon (n = 3.47). Therefore there is a lower index contrast for the InP membrane waveguides. This can lead to higher radiative loss in the bends, and stronger scattering from sidewalls. Therefore a larger bending loss as compared to traditional arc bends is required. Figure 1(a) depicts the calculated 90° bending loss in silicon (Si) and InP membrane waveguides. The waveguide dimensions are 450 × 220 nm and 400 × 300 nm respectively. The black square is the reported value for a silicon waveguide [6], matching well with the simulation. (b) Simulated 90° bending loss in InP membrane waveguides with different footing values. Red, green and blue squares represent the loss of the proposed sharp bent at corresponding footings.

Moreover, in the InP membrane platform, a certain thickness of footing (~20 nm) is sometimes incorporated, to protect important epitaxial layers and bonding interfaces beneath the waveguide layer during the processing. The existence of a footing has no influence on the mode propagation properties of straight waveguides. But it can be an extra source of loss in waveguide bends, as shown in Fig. 1(b). Significant increase of bending loss is observed in the presence of footing, and the loss is very sensitive to the thickness variation of the footing. Therefore a solution that can avoid both problems presented in Fig. 1(a) and (b) is greatly desired.

In this letter we propose a novel waveguide bend design, using the principle of total internal reflection (TIR) to improve the performance as well as reduce the footprint. The design is much less sensitive to the footing as compared to traditional arc bends. The proposed design as well as traditional arc bends are fabricated and experimentally analyzed and compared. The results of the novel bend show an effective bending radius of only 0.96 μm and a low bending loss over a wide wavelength band.
II. DESIGN AND SIMULATION

The cross-sectional view of the typical InP membrane passive waveguide is shown in Fig. 2(a). The InP membrane is bonded to the silicon wafer with BCB polymer. The processing of the membrane devices is based on electron-beam lithography (EBL) and dry etching. The resulting waveguide dimensions of 400 nm wide by 300 nm high ensure single-mode operation around the wavelength of 1550 nm, while the ∼20 nm footing left in the etched region protects the epitaxial and bonding layers during the processing.

The schematic diagram of the traditional arc bends is shown in Fig. 2(b). Radiative loss is the major contribution to the total bending loss. In the bends, the optical mode will be pushed towards the outer edge of the waveguide, leaving a much stronger evanescent field outside the waveguide core. It increases dramatically as the bending radius decreases, as can be seen in Fig. 1(b). To minimize extra loss due to mode mismatch at the junctions between straight waveguide and arc bend, and between two arc bends with opposite curvatures, lateral offsets (shown as $o_1$ and $o_2$ in Fig. 2(b)) are introduced [8]. Sharper bends require much larger offsets since the mode mismatch is more severe. For a relatively large radius such as 10 μm, the offsets $o_1$ and $o_2$ are 4 and 8 nm respectively. When the radius reduces to 1.5 μm, the $o_1$ and $o_2$ can be as large as 30 and 60 nm.

As motivated by the challenges discussed in the introduction, we present an ultra-sharp bend design using the TIR principle. A schematic diagram of such a sharp bend on InP membrane is shown in Fig. 3(a). This concept utilizes a 45° facet for sharp turning of the light, and an extended square region for loss optimization. The concept was originally proposed by [9]. But it was based on 2D assumptions, and has not ever been verified in any real waveguide platforms. In this work, the structure is simulated and optimized with a 3D finite difference time domain (FDTD) algorithm. An example of the calculated instantaneous electric field distribution in this structure, for transverse electric (TE) mode input, is shown in Fig. 3(b). As can be seen the TE mode is bent 90° at the 45° facet and is almost lossless.

To examine the geometric tolerance of this component, the optical transmission is calculated at 1550 nm wavelength as a function of the structure parameters $a$ and $b$, as shown in Fig. 4(a). The best optical transmission of 0.97 is marked in the figure as a white cross, corresponding to $a$ and $b$ values of 515 nm and 760 nm respectively. From the figure one can also see that when the $a$ and $b$ value deviate ±100 nm from the optimum value, the optical transmission of the device only decreases from 0.97 (−0.13 dB) to about 0.9 (−0.46 dB). This indicates a very high fabrication tolerance of the device, which is very suitable for the large-scale membrane process.

The wavelength dependence of the transmission and reflection of the device is shown in Fig. 4(b) and (c). As can be seen, very low wavelength dependence is observed. The optical transmission spectrum over the entire 100 nm wavelength band has only 0.07 dB variation. The reflection back into the input waveguide is low (below −20 dB) over the 100 nm wavelength band.

Another advantage of this sharp bend structure is the elimination of mode mismatch existing in traditional arc bend connections. Therefore there will be no lateral offsets and no connection loss between different bends. The cascade of the sharp bend structures to form a 180° bend is also studied. As can be seen in Fig. 3(b), the extended square region acts as a buffer to reduce the mode leakage in the bend. Therefore it contains minor optical power. When two such structures are connected to form a 180° bend, it is necessary to avoid coupling between these minor optical fields in the square regions, as shown schematically in Fig. 5(a). The gap width $g$ is optimized to be 150 nm to avoid this coupling. This is
Fig. 5. (a) Schematic diagram of the cascaded 180° bend. (b) Calculated instantaneous electric field distribution for TE mode input in the cascaded structure.

Table I

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<tr>
<th>Parameters of the Fabricated Bending Test Structures</th>
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<td>Type</td>
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sufficiently small to ensure the compactness of the bends. The calculated instantaneous electric field distribution for TE mode input in the cascaded 180° bend with \( g = 150 \) nm is shown in Fig. 5(b).

Lastly, the influence of waveguide footings to the device performance is verified. The bending loss for the proposed structure is calculated when the footing thickness is 0, 20 and 30 nm respectively, shown as the squares in Fig. 1(b). As can be seen, due to the advantage of reflection-based bending, the influence of the thin footing is much reduced. The bending loss only increases from 0.13 dB to 0.24 dB as the footing increases from 0 to 30 nm. On the other hand, the traditional arc bend with 1 µm radius experiences much higher losses: from 0.37 dB to 0.95 dB at the same footing conditions. Therefore it is clear that the proposed sharp bend structure is more suited for complex design and processing situations, where footings are inevitable.

III. Fabrication and Demonstration

Both the proposed sharp bends and the traditional arc bends are fabricated in an InP membrane chip. The details of the processing related to this work can be found in [10] and [11]. To evaluate the loss of a single 90° bend, the bends are cascaded in S shapes to accumulate sufficient loss for accurate measurement. The parameters of the fabricated bends are summarized in Table 1. Scanning electron microscope (SEM) pictures of the fabricated waveguide bends are shown in Fig. 6.

Fiber grating couplers are realized at the two ends of the fabricated cascades of bends for optical transmission characterization. The input and output optical fibers are placed under an angle of 9° with respect to the surface normal. Commercial tunable laser and power meter modules are used as the light source and the detector. The wavelength of the tunable laser is scanned to evaluate the spectral response of the bends. Before the input fiber, a polarization controller is used to match the polarization of light to that of the grating, which is TE. Beside the cascaded bends, straight waveguides are implemented for the calibration of the loss from fiber grating couplers. Therefore the loss per 90° bend can be derived by dividing the loss difference between cascaded bends and straight waveguide by the number of the bends.

The measured bending losses of the proposed sharp bend and the reference arc bends are shown in Fig. 7. As can be seen for arc bends, the loss increases significantly as the radius reduces. For relatively large radii of 5 and 10 µm, the loss is very low (0.03 dB per 90° bend). Furthermore the bending loss for 5 µm and 10 µm are almost the same, indicating that for such large bending radii, the radiative loss is no longer dominant. The interaction of the optical mode with the outer sidewall of the bends is relatively weak, resulting in low bending loss. On the other hand, for relatively small bending radii (1.5 and 2 µm), higher losses are observed due to the stronger radiative loss as well as stronger scattering at the sidewall. Therefore the bending loss can be as high as 0.2 dB per 90° bend. It is also worth mentioning that the offsets at arc junctions aim for loss reduction. However at the same time those abrupt discontinuities at the junctions can introduce strong reflections and scattering, especially for a very small radius with a large offset, as can be seen from the resonance-like features in the red curve (\( r = 1.5 \) µm) in Fig. 7. The measured results of the proposed sharp bend show promising performance. The bending loss is as low as 0.13 dB, in good agreement with the simulations, which is much lower than that for 1.5 µm and 2 µm arc radii, especially giving the fact that its effective radius is below 1 µm. The spectral
response shows a very large operating wavelength, which is comparable to the arc bends.

IV. CONCLUSIONS

In conclusion, we have presented a sharp waveguide bend design for membrane based optical waveguides. It has advantages such as low loss (0.13 dB per 90°), small radius (<1 µm), flat wavelength response over 100 nm, elimination of junction offsets and ease of design and fabrication. It is also advantageous over traditional arc bends for its much reduced sensitivity to waveguide footings. This structure was fabricated together with traditional arc bends. Measurement results confirmed the promising performance of this sharp bend. In the future it can be used as a basic building block for InP membrane photonic platforms.

REFERENCES